

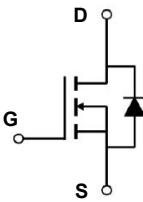
## Features

- $V_{DS}=100V, I_D=70A$
- $R_{ds(on)}(typ)=9.2m\Omega @ V_{gs}=10V$
- 100% Avalanche Tested
- 100%  $R_g$  Tested
- Lead-Free (RoHS Compliant)

## Applications

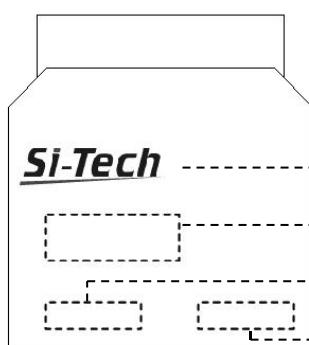
- DC Motor Control
- DC-DC Converters
- BMS
- SMPS
- Automotive Environment

## Internal Circuit and Pin Description

	
Package	
Package Code	TO-252

M

## Package Marking



- Company
- Part No. and Package Code
- Assembly Information
- Lot No.

## Absolute Maximum Ratings ( $T_c=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Value	Units
$V_{DSS}$	Drain-Source Voltage	100	V
$I_D$	Continuous Drain Current ( $T_c=25^\circ C$ )	70	A
	Continuous Drain Current ( $T_c=100^\circ C$ )	44	A
$I_{DM}$	Pulsed Drain Current (Note 1)	280	A
$V_{GS}$	Gate-Source Voltage	$\pm 25$	V
$E_{AS}$	Single Pulsed Avalanche Energy (Note 2)	272	mJ
$P_D$	Maximum Power Dissipation ( $T_c=25^\circ C$ )	109	W
	Derating Factor above $25^\circ C$	0.87	W/ $^\circ C$
$T_J$	Operating Junction Temperature Range	-55 to +150	$^\circ C$
$T_{STG}$	Storage Temperature Range	-55 to +150	$^\circ C$

**Thermal Characteristics**

Symbol	Parameter	Value	Units
R <sub>th j-c</sub>	Thermal Resistance, Junction to case	1.14	°C/W

**Electrical Characteristics** ( $T_c=25^\circ\text{C}$  unless otherwise noted)

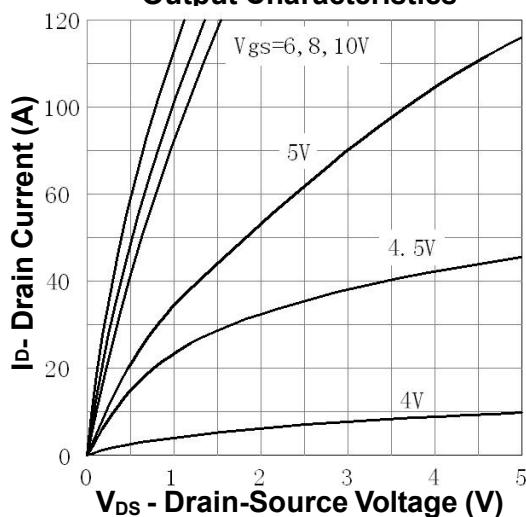
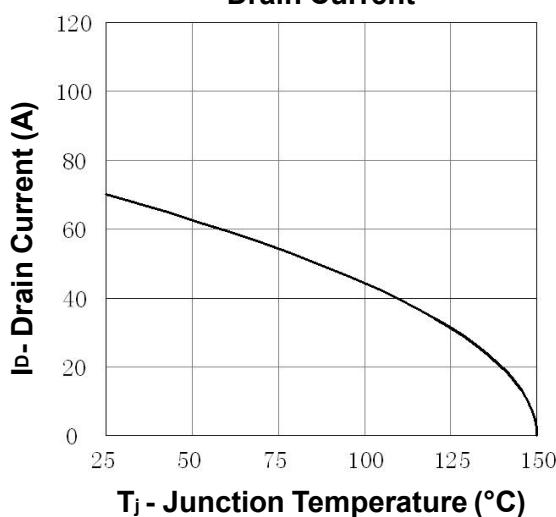
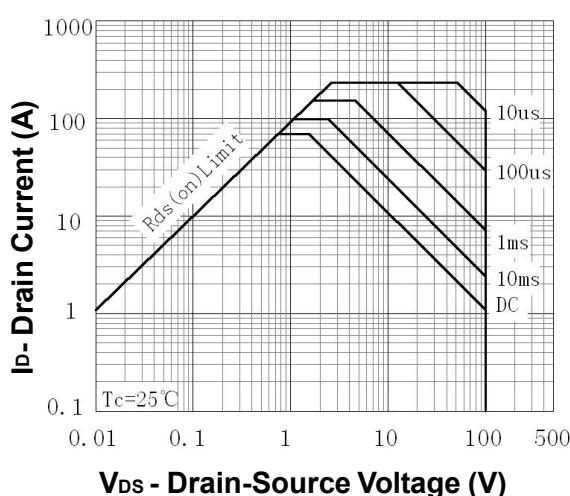
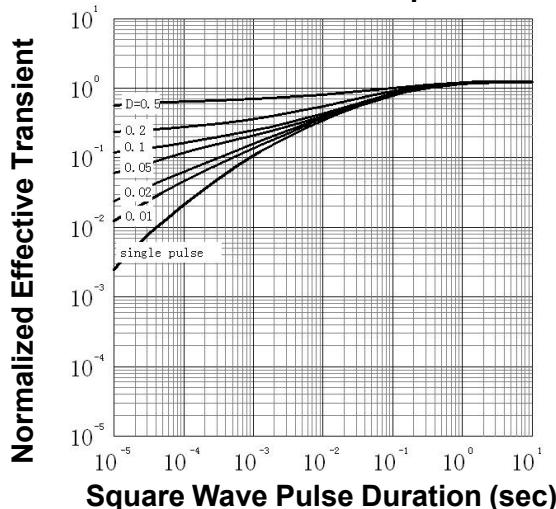
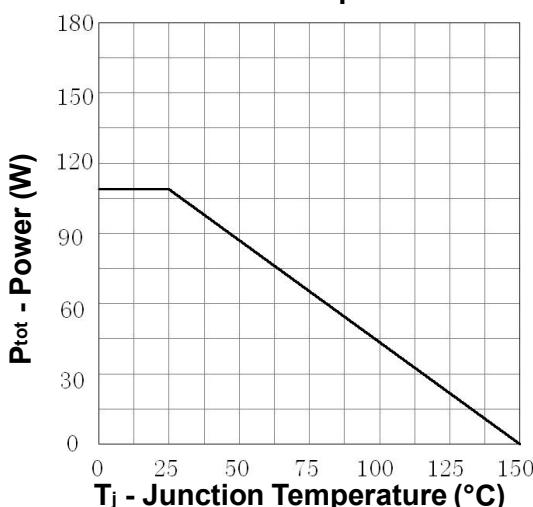
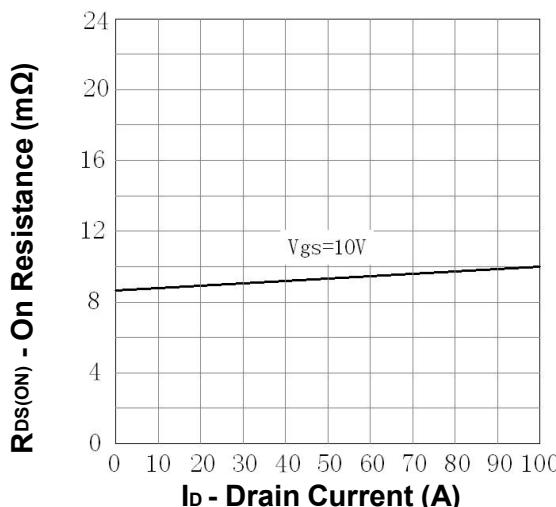
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	100	-	-	V
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =95V, V <sub>GS</sub> =0V	-	-	1	uA
I <sub>GSS</sub>	Gate Leakage Current, Forward	V <sub>GS</sub> =25V, V <sub>DS</sub> =0V	-	-	100	nA
	Gate Leakage Current, Reverse	V <sub>GS</sub> =-25V, V <sub>DS</sub> =0V	-	-	-100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>GS</sub> =V <sub>DS</sub> , I <sub>D</sub> =250uA	2.4	3	3.6	V
R <sub>D(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =40A	7.3	9.2	11	mΩ
Q <sub>g</sub>	Total Gate Charge	V <sub>DD</sub> =72V V <sub>GS</sub> =10V I <sub>D</sub> =40A (Note 3)	-	82	-	nC
Q <sub>gs</sub>	Gate-Source Charge		-	16	-	nC
Q <sub>gd</sub>	Gate-Drain Charge		-	21	-	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =37.5V, V <sub>GS</sub> =10V I <sub>D</sub> =45A, R <sub>G</sub> =4.7Ω T <sub>c</sub> =25°C (Note 3)	-	22	-	ns
t <sub>r</sub>	Turn-on Rise Time		-	46	-	ns
t <sub>d(off)</sub>	Turn-off Delay Time		-	68	-	ns
t <sub>f</sub>	Turn-off Fall Time		-	60	-	ns
R <sub>g</sub>	Gate Resistance	V <sub>DS</sub> =0V, V <sub>GS</sub> =0V, f=1MHz	-	0.9	-	Ω
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =25V V <sub>GS</sub> =0V f = 1MHz	-	3247	-	pF
C <sub>oss</sub>	Output Capacitance		-	367	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		-	248	-	pF

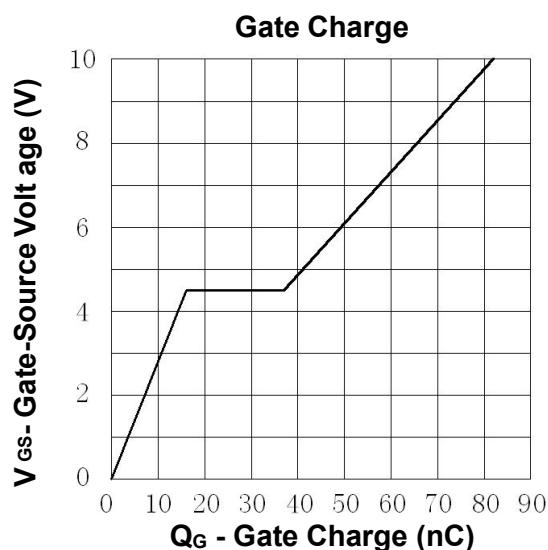
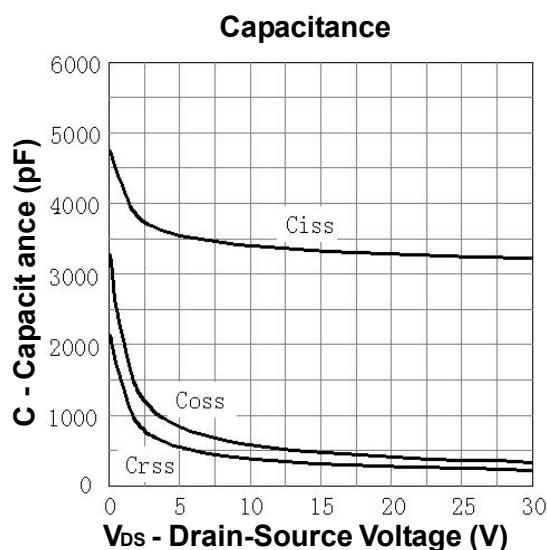
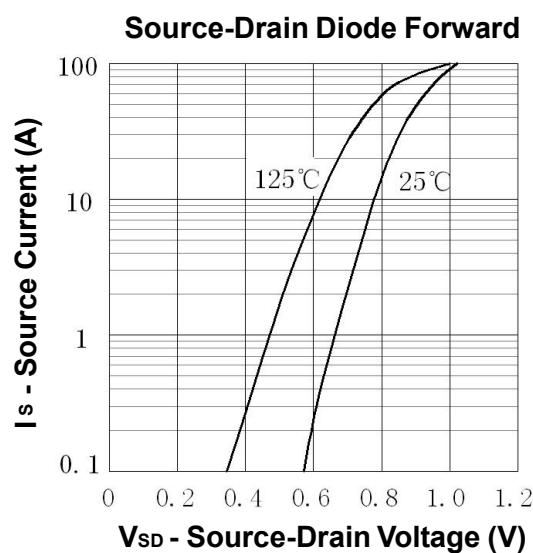
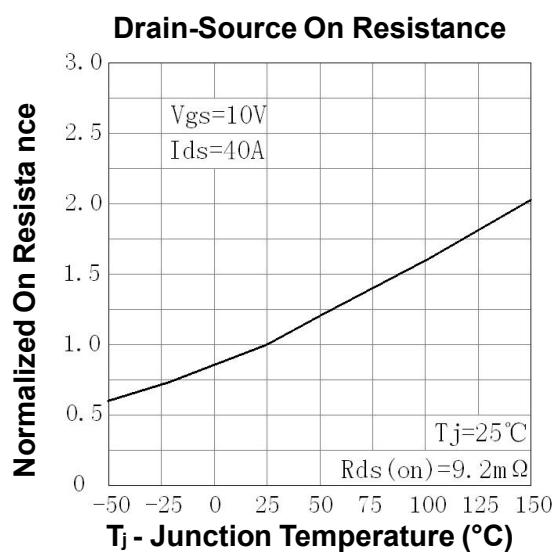
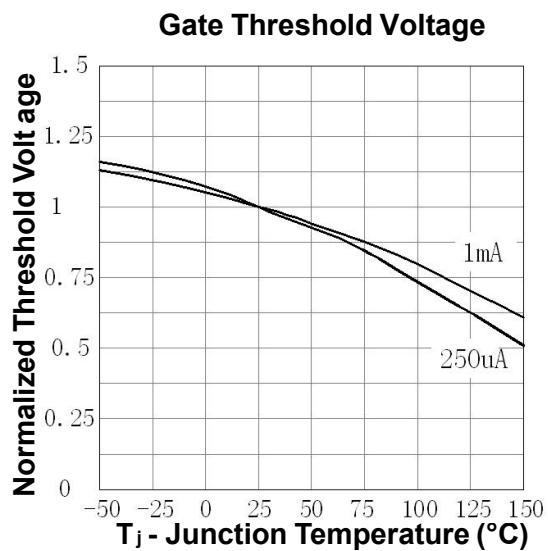
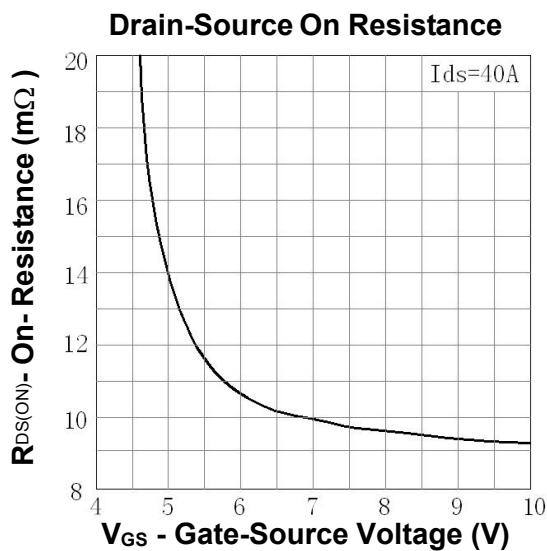
**Source-Drain Diode Characteristics** ( $T_c=25^\circ\text{C}$  unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
I <sub>s</sub>	Continuous Source Diode Forward Current	-	-	70	A	
I <sub>SM</sub>	Pulsed Source Diode Forward Current (Note 1)	-	-	280	A	
V <sub>SD</sub>	Forward On Voltage	V <sub>GS</sub> =0V, I <sub>s</sub> =45A	-	0.88	1	V
t <sub>rr</sub>	Reverse Recovery Time	V <sub>GS</sub> =0V, I <sub>s</sub> =45A dI <sub>F</sub> /dt = 100A/us	-	32	-	ns
	Reverse Recovery Charge		-	52	-	nC

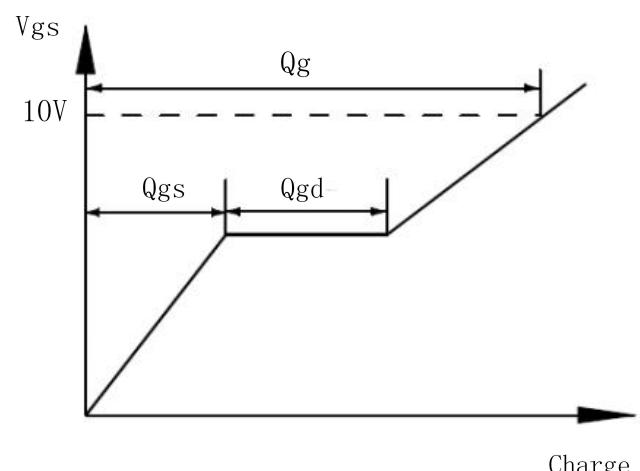
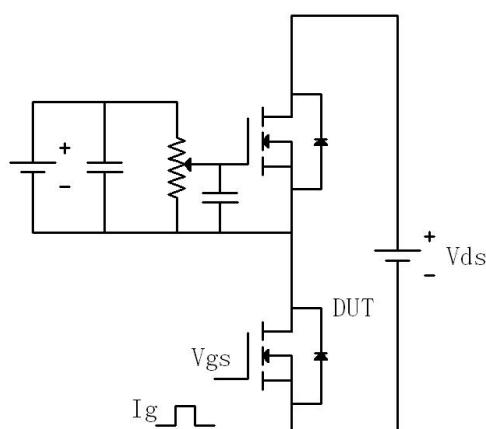
**Notes:**

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. L=0.5mH, V<sub>DD</sub>=64V, R<sub>G</sub>=25Ω, Starting T<sub>J</sub>=25°C
3. Pulse Width ≤ 300 us; Duty Cycle≤2%

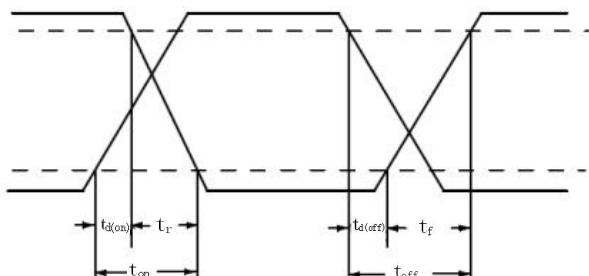
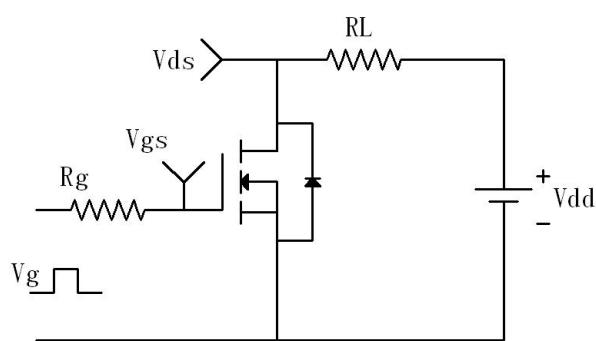
**Typical Characteristics****Output Characteristics****Drain Current****Safe Operation Area****Thermal Transient Impedance****Power Dissipation****Drain-Source On Resistance**



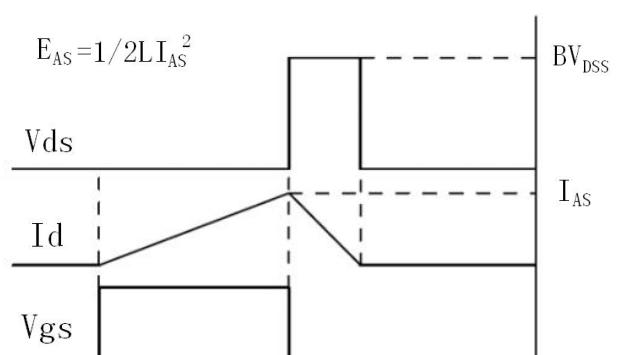
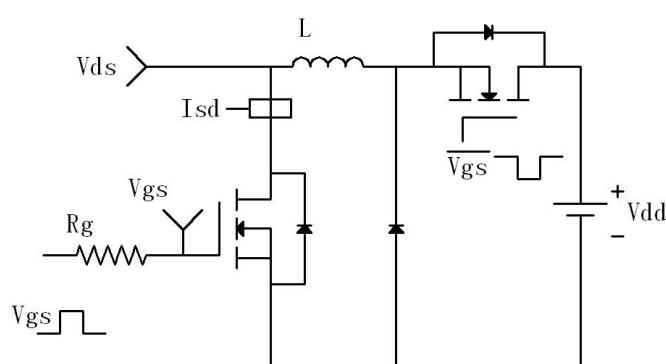
## Gate Charge Test Circuit and Waveforms



## Switching Time Test Circuit & Waveforms

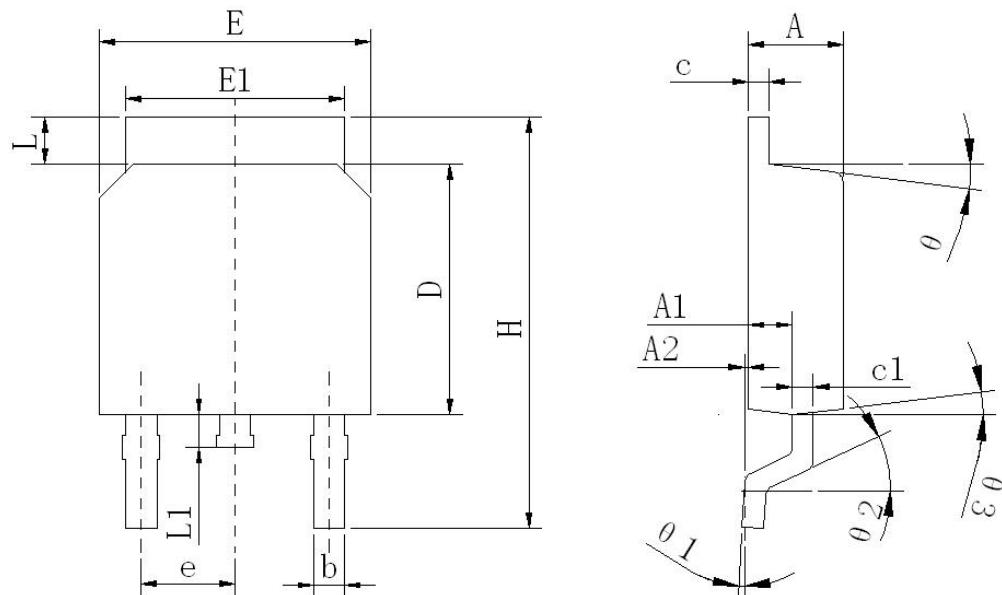


## Avalanche Test Circuit & Waveforms

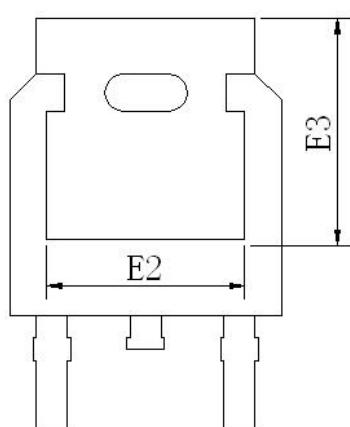


## Package Outline

TO252



UNIT:mm



<b>SYMBOL</b>	<b>MIN</b>	<b>NOM</b>	<b>MAX</b>
<b>A</b>	2.25	2.30	2.35
<b>A1</b>	1.02	1.07	1.12
<b>A2</b>	0.05	0.1	0.15
<b>b</b>	0.71	0.76	0.81
<b>c</b>	0.46	0.51	0.56
<b>c1</b>	0.46	0.51	0.56
<b>D</b>	6.05	6.10	6.15
<b>E</b>	6.55	6.60	6.65
<b>E1</b>	5.23	5.33	5.43
<b>E2</b>	4.73	4.83	4.93
<b>E3</b>	5.30	5.40	5.50
<b>e</b>	2.286 BSC		
<b>H</b>	9.82	10.02	10.22
<b>L</b>	0.96	1.01	1.06
<b>L1</b>	0.7	0.8	0.9
<b>Theta</b>	5°	7°	9°
<b>Theta1</b>	1°	3°	5°
<b>Theta2</b>	23°	25°	27°
<b>Theta3</b>	5°	7°	9°